NSN 5961-00-152-8523

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View Online at https://aerobasegroup.com/nsn/5961-00-152-8523	
Inclosure Material:	
Metal	
Overall Length:	
Between 0.240 inches and 0.260 inches	
Terminal Length:	
Between 1.500 inches and 1.750 inches	
Overall Diameter:	
Between 0.335 inches and 0.370 inches	
Internal Configuration:	
Junction contact	
Electrode Internally-electrically Connected To Case:	
Collector	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
100.0 collector to base voltage/static/emitter open and 80.0 collector-to-emitter, resistance between base and emitter and 7.0 emitter	tc
base voltage, static, collector open	
Current Rating Per Characteristic:	
500.00 milliamperes source cutoff current	
Power Rating Per Characteristic:	
3.0 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Special Features:	
Junction pattern arrangement: npn	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification	ì
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain	
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/225 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	

NI

Demilitarization:

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